Docket No. 241807US2DIV

IN RE APPLICATION OF: Toshiaki IWAMATSU, et al.

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

GAU:

SERIAL NO: New Application			EXAMINER:			
FILED:	Herewith					
FOR:	SEMICONDUCTOR DEVICE AND METHOD OF MANUFACTURING THE SAME					
REQUEST FOR PRIORITY						
	SIONER FOR PATENTS DRIA, VIRGINIA 22313					
SIR:						
pursua	ant to the provisions of $35~\mathrm{U}_{\odot}$					
☐ Full benefit of the filing date(s) of §119(e):		U.S. Provisional Application(s) <u>Application No.</u>	is claimed p Date I	oursuant to th Filed	e provisions of 35 U.S.C.	
Appli the pr	cants claim any right to prior ovisions of 35 U.S.C. §119,	rity from any earlier filed applica as noted below.	itions to wh	ich they may	be entitled pursuant to	
In the mat	tter of the above-identified ap	oplication for patent, notice is he	reby given 1	that the application	cants claim as priority:	
COUNTI Japan	RY	APPLICATION NUMBER 2000-354043		MONTH/DA November 21,		
□ are	copies of the corresponding (e submitted herewith					
	ill be submitted prior to payn					
were filed in prior application Serial No. 09/985,020 filed November 1, 2001						
were submitted to the International Bureau in PCT Application Number Receipt of the certified copies by the International Bureau in a timely manner under PCT Rule 17.1(a) has been acknowledged as evidenced by the attached PCT/IB/304.						
□ (A	A) Application Serial No.(s) v	were filed in prior application Se	rial No.	filed	; and	
☐ (B) Application Serial No.(s)						
	☐ are submitted herewith					
☐ will be submitted prior to payment of the Final Fee						
			Respectful	ly Submitted	,	
				SPIVAK, Mc NEUSTADT	CLELLAND, 1, P.C. / Decerles	
	er Number		Gregory J. Maier			
22850			Registratio	on No. 25,59	99	
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(OSMMN 05/03)			Registration	on No. 28,8	70	
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